Power MOSFET 60 V, 24 mΩ, 26 A, Single N–Channel

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFS5826NLWF Wettable Flanks Product
- AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices and RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parar	Symbol	Value	Unit		
Drain-to-Source Voltage			V _{DSS}	60	V
Gate-to-Source Voltage	V _{GS}	±20	V		
Continuous Drain Cur-		T _{mb} = 25°C	۱ _D	26	А
rent R $_{\Psi J-mb}$ (Notes 1, 2, 3, 4)	Steady	T _{mb} = 100°C		19	
Power Dissipation	State	T _{mb} = 25°C	PD	39	W
R _{ΨJ-mb} (Notes 1, 2, 3)		$T_{mb} = 100^{\circ}C$		19	
Continuous Drain Cur-		$T_A = 25^{\circ}C$	I _D	8.0	А
rent R _{θJA} (Notes 1, 3, 4)	Steady State	T _A = 100°C		6.0	
Power Dissipation		T _A = 25°C	PD	3.6	W
R _{θJA} (Notes 1 & 3)		T _A = 100°C		1.8	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	130	А
Operating Junction and Storage Temperature			T _J , T _{stg}	– 55 to + 175	°C
Source Current (Body Diode)			۱ _S	32	А
Single Pulse Drain-to-Source Avalanche Energy (T _J = 25°C, V _{DD} = 24 V, V _{GS} = 10 V, $I_{L(pk)}$ = 20 A, L = 0.1 mH, R _G = 25 Ω)			E _{AS}	20	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Mounting Board (top) - Steady State (Notes 2, 3)	$R_{\Psi J-mb}$	3.9	°C/W
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	42	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Psi (Ψ) is used as required per JESD51–12 for packages in which substantially less than 100% of the heat flows to single case surface.

3. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

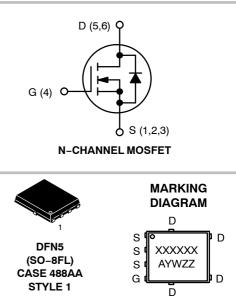
4. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
60 V	24 m Ω @ 10 V	00 1
00 V	32 mΩ @ 4.5 V	26 A



A = Assembly Location Y = Year W = Work Week ZZ = Lot Traceability

ORDERING INFORMATION

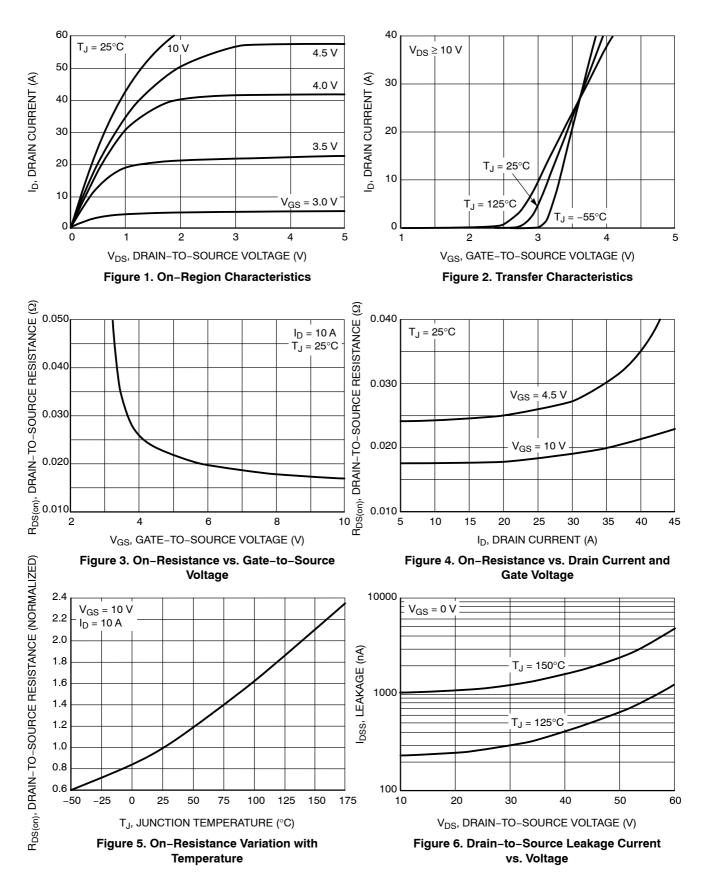
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

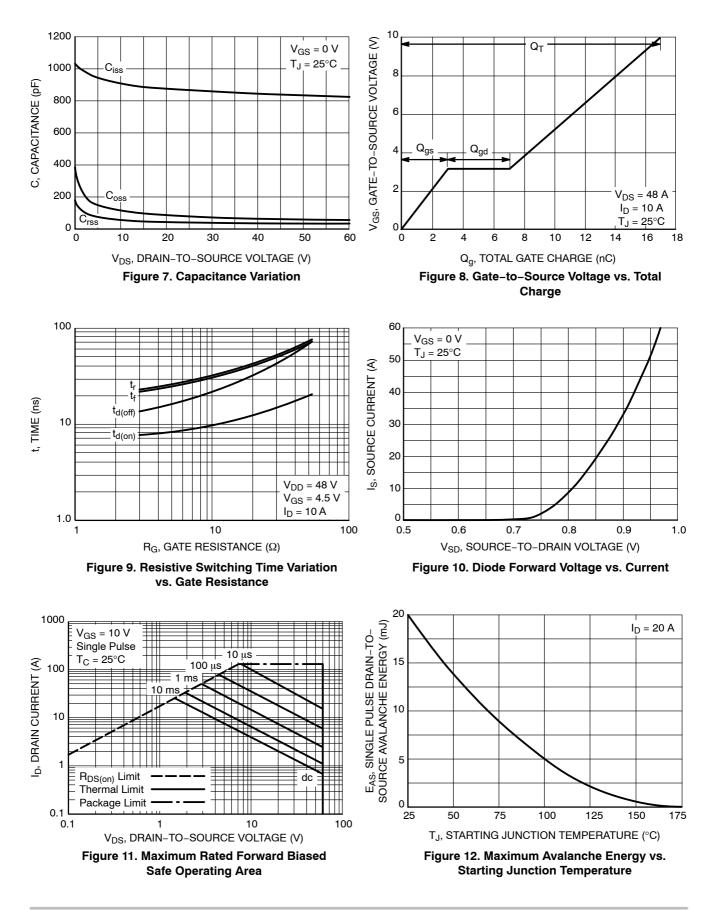
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	-	-			-	-	-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		60			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$, $T_J = 25^{\circ}C$				1.0	μΑ
			T _J = 125°C			10	1
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = \pm 20 V				±100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	V_{GS} = V_{DS} , I_D = 250 μ A		1.5		2.5	V
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 10 A V_{GS} = 4.5 V, I _D = 10 A			18	24	mΩ
					24	32	1
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _D = 5 A			8.0		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{iss}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V			850		pF
Output Capacitance	C _{oss}				85		-
Reverse Transfer Capacitance	C _{rss}				50		
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 48 V, I_D = 10 A V_{GS} = 10 V, V_{DS} = 48 V, I_D = 10 A			9.1		nC
Threshold Gate Charge	Q _{G(TH)}				1.0		
Gate-to-Source Charge	Q _{GS}				3.0		
Gate-to-Drain Charge	Q _{GD}				4.0		
Total Gate Charge	Q _{G(TOT)}				17		nC
SWITCHING CHARACTERISTICS (No	ote 6)						
Turn-On Delay Time	t _{d(ON)}				9.0		
Rise Time	t _r	V_{GS} = 4.5 V, V_{DS} = 48 V, I_{D} = 10 A, R_{G} = 2.5 Ω			32		ns
Turn-Off Delay Time	t _{d(OFF)}				15		
Fall Time	t _f				24		
DRAIN-SOURCE DIODE CHARACTER	ISTICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V, T_{J} = 25^{\circ}C T_{J} = 125^{\circ}C T_{J} = 125^{\circ}C$	$T_{\rm J} = 25^{\circ}C$		0.8	1.2	V
				0.7		1	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dls/dt = 100 A/μs, I _S = 10 A			15		
Charge Time	ta				11		ns
Discharge Time	t _b				4.0		1
Reverse Recovery Charge	Q _{RR}				11		nC

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

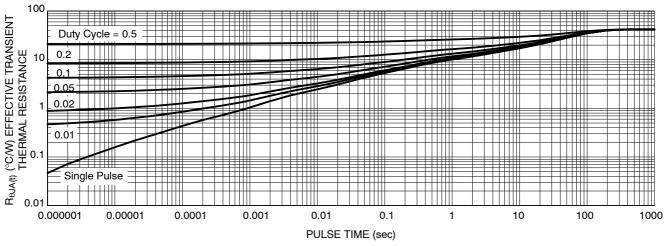


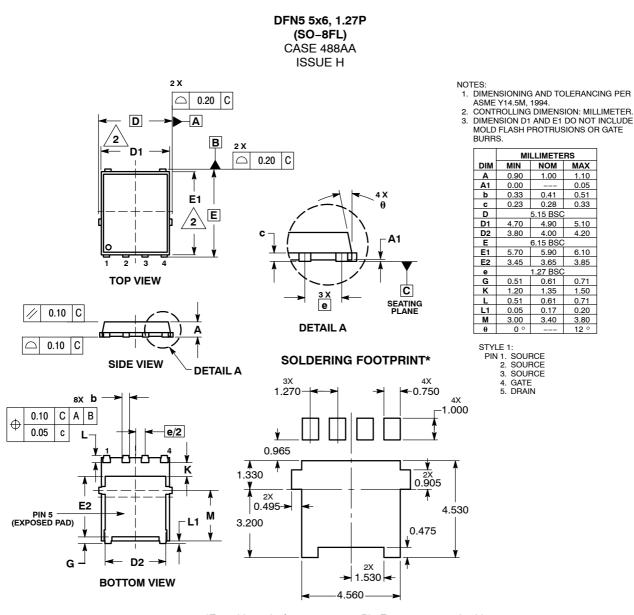
Figure 13. Thermal Response

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS5826NLT1G	V5826L	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5826NLWFT1G	5826LW	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5826NLT3G	V5826L	DFN5 (Pb–Free)	5000 / Tape & Reel
NVMFS5826NLWFT3G	5826LW	DFN5 (Pb–Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemic.com/site/pdf/Patent-Marking.pdf. SCILLC protects for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC products for any paricular purpose, nor other application is intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, and claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the personal injury or death associated with such unintended or unauthorized application scan and easing out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application. Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims,

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421-33-700-2910

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NVMFS5826NLT1G